▲ 〈SMALL-SIGNAL TRANSISTOR〉

2SC3242,2SC3242A

FOR LOW FREQUENCY POWER AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

DESCRIPTION

2SC3242,2SC3242A is a silicon NPN epitaxial type transistor designed for small type motor drive, solenoid drive and power supply application.

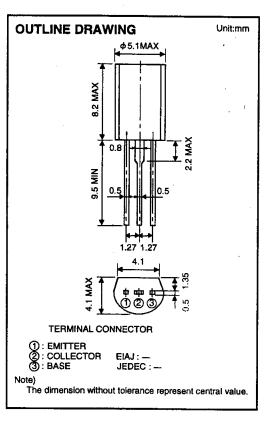
Complementary with 2SA1282,2SA1282A.

FEATURE

- High collector current Ic=2A
- Low VCE(sat)
- VCE(sat)=0.17V typ (@IC=1A)
- ●High hFE hFE=150 to 800
- High collector dissipation Pc=900mW

APPLICATION

Small type motor drive, power supply for VCR, deck, player.



MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Rat	Unit		
Cyntoor	i didificici	2SC3242	2SC3242A	Unit	
Vсво	Collector to Base voltage	20	20	V	
VEBO	Emitter to Base voltage	6	6	V	
VCEO	Collector to Emitter voltage	16	20	٧	
Ісм	Peak Collector current		A		
lc	Collector current		A		
Pc	Collector dissipation(Ta=25°C)	9	mW		
Tj	Junction temperature	+1	r		
Tstg	Storage temperature	-55 to	r		

ELECTRICAL CHARACTERISTICS (Ta=25℃)

Symbol	Parameter	Test conditions	Limits						1
			2SC3242				2SC3242/	1	Unit
			Min	Тур	Max	Min	Тур	Max	1
V(BR)CBO	C to B break down voltage	$I_{C}=10 \mu A, I_{E}=0$	20	1	1	20			V
V(BR)EBO	E to B break down voltage	$IE=10 \mu A, IC=0$	5	1		6			V
V(BR)CEO	C to E break down voltage	Ic=2mA,Rв∈=∞	16		1	20			V V
Ісво	Collector cut off current	VCB=16V,IE=0			0.2	-		0.2	ЦA
IEBO	Emitter cut off current	VEB=4V,IC=0			0.2	****	-	0.2	μA
hfe ×	DC forward current gain	VCE=4V,IC=100mA	150		800	150		500	
VCE(sat)	C to E saturation voltage	Ic=1A,I8≃50mA		0.17	0.3		0.17	0.3	V
fr	Gain band width product	VCE=2V,IE=-10mA		80			80		MH
Cob	Collector output capacitance	VCB=10V,IE=0,f=1MHz		28	1		28		0F
: It shows h	FE classification in right table				· · · · · · · · · · · · · · · · · · ·	·	···		
	u u			ltern E			F		G
			hFE 150 to		300	250 to 500		400 to 800	

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1.0

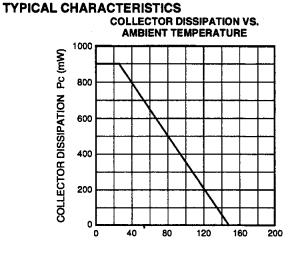
0.8

0.6

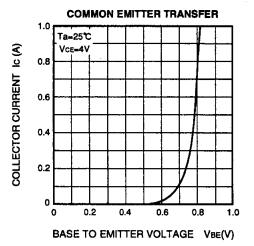
0.4

0.2

COLLECTOR CURRENT Ic (mA)



AMBIENT TEMPERATURE Ta(°C)



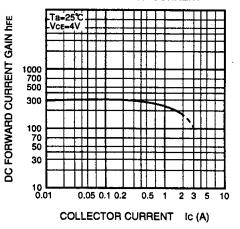
COLLECTOR TO EMITTER SATURATION

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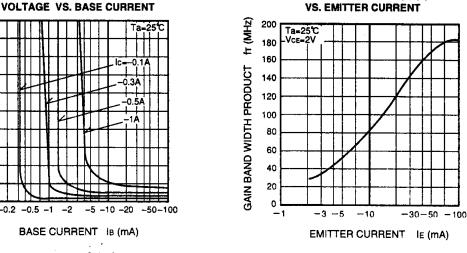
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COLLECTOR TO EMITTER VOLTAGE VCE(V)

DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT



GAIN BAND WIDTH PRODUCT **VS. EMITTER CURRENT**



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Vce(V) 2.0

EMITTER VOLTAGE

CULLECTOR TO

1.8

1.6

1.4

1.2

1.0

0.8

0.6

0.4

0.2

0

-0.1 -0.2 -0.5 -1 -2

4.0 Ta-25°C

3.5

3.0

2.5

20 1.5

0.5mA

4

1.0

Bad

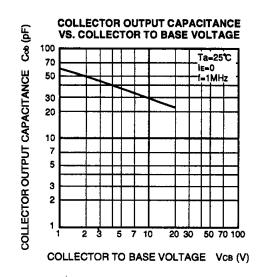
5

COMMON EMITTER OUTPUT

(SMALL-SIGNAL TRANSISTOR)

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http://www.idc-com.co.jp 6-41, TSUKUBA, ISAHAYA, NAGASAKI, 854-0065, JAPAN

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